

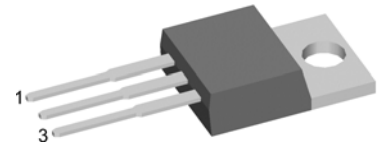
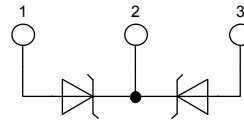
# Schottky Diode

High Performance Schottky Diode  
 Low Loss and Soft Recovery  
 Common Cathode

$V_{RRM} = 30\text{ V}$   
 $I_{FAV} = 2 \times 30\text{ A}$   
 $V_F = 0.49\text{ V}$

Part number

**DSB 60 C 30 PB**



Backside: cathode

### Features / Advantages:

- Very low  $V_f$
- Extremely low switching losses
- low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

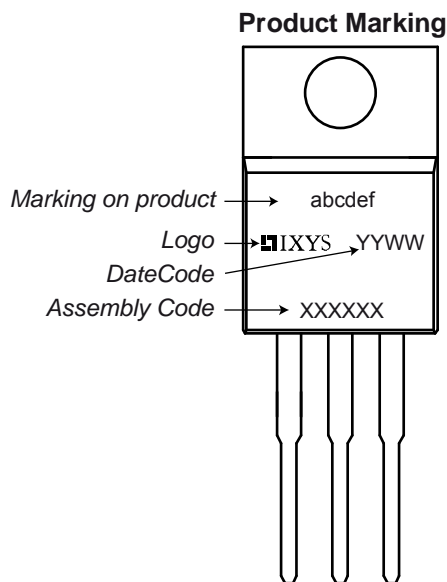
### Package:

- Housing: TO-220
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Symbol	Definition	Conditions	Ratings			Unit	
			min.	typ.	max.		
$V_{RRM}$	max. repetitive reverse voltage				30	V	
$I_R$	reverse current	$V_R = 30\text{ V}$			20	$\mu\text{A}$	
		$V_R = 30\text{ V}$			80	mA	
$V_F$	forward voltage	$I_F = 30\text{ A}$			0.55	V	
		$I_F = 60\text{ A}$			0.74	V	
		$I_F = 30\text{ A}$	$T_{VJ} = 125^\circ\text{C}$			0.49	V
		$I_F = 60\text{ A}$	$T_{VJ} = 125^\circ\text{C}$			0.73	V
$I_{FAV}$	average forward current	rectangular, $d = 0.5$			30	A	
$V_{FD}$	threshold voltage	} for power loss calculation only			0.22	V	
$r_F$	slope resistance				8	$\text{m}\Omega$	
$R_{thJC}$	thermal resistance junction to case				0.85	K/W	
$T_{VJ}$	virtual junction temperature		-55		150	$^\circ\text{C}$	
$P_{tot}$	total power dissipation				130	W	
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}$ (50 Hz), sine			330	A	
$C_J$	junction capacitance	$V_R = \text{tbd V}$ ; $f = 1\text{ MHz}$		tbd		pF	

Symbol	Definition	Conditions	Ratings			Unit
			min.	typ.	max.	
$I_{RMS}$	RMS current	per pin <sup>1)</sup>			50	A
$R_{thCH}$	thermal resistance case to heatsink			0.50		K/W
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				2		g
$M_D$	mounting torque		0.4		0.8	Nm
$F_C$	mounting force with clip		20		60	N

<sup>1)</sup>  $I_{RMS}$  is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.  
 In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

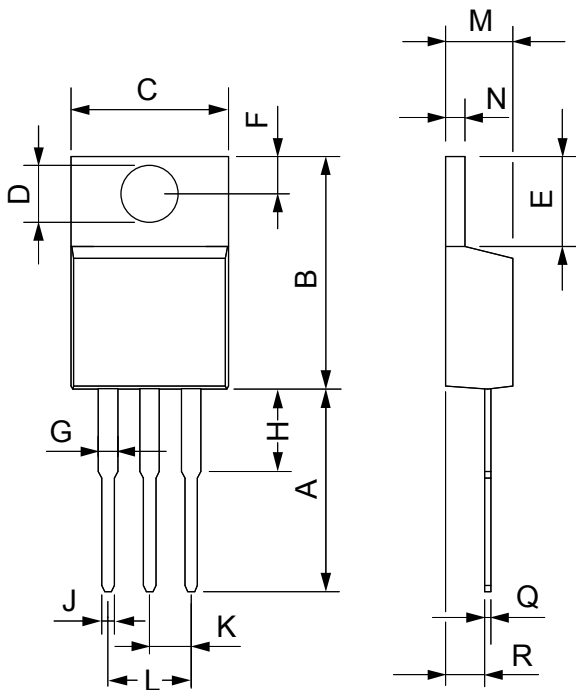

**Part number**

D = Diode  
 S = Schottky Diode  
 B = ultra low VF  
 60 = Current Rating [A]  
 C = Common Cathode  
 30 = Reverse Voltage [V]  
 PB = TO-220AB (3)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSB 60 C 30 PB	DSB60C30PB	Tube	50	

Similar Part	Package	Voltage class
DSB60C30HB	TO-247	30

Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.35	0.56	0.014	0.022
R	2.29	2.79	0.090	0.110